# Honeywell

Preliminary

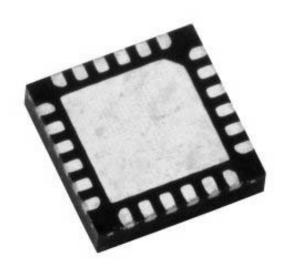
# 31.0 dB, DC-4GHz, 5 Bit Parallel Digital Attenuator

#### **Features**

- Very Low DC Power Consumption
- Attenuation In Steps From 1 dB To 31 dB
- Single Or Dual Power Supply Voltages
- Parallel Data Interface
- 50 Ohm Compatible Impedance
- Space Saving LPCC<sup>™</sup> Surface Mount Packaging



The Honeywell HRF-AT4520 is a 5-bit digital attenuator that is ideal for use in broadband communication system applications that require accuracy, speed and low power consumption. The HRF-AT4520 is manufactured with Honeywell's patented Silicon On Insulator (SOI) CMOS manufacturing technology, which provides the performance of GaAs with the economy and integration capabilities of conventional CMOS.



HRF-AT4520 in LPCC™ Package

### RF Electrical Specifications @ + 25°C

Parameter	Test Condition	Frequency	Minimum	Typical	Maximum	Units
Insertion Loss		DC - 0.5 GHz		1.8		dB
		2.0 GHz		2.7		dB
		3.0 GHz				dB
		4.0 GHz				dB
1dB Compression	VSS = 0V, Input Power	DC – 2.0 GHz		24		dBm
1dB Compression	VSS = - VDD, Input Power	DC – 2.0 GHz		29		dBm
Input IP3	VSS = 0V Two-tone inputs Up To +5 dB @ 0 dB Attenuation	DC - 2.0 GHz		38		dBm
Input IP3	V <sub>ss</sub> = - V <sub>DD</sub> Two-tone inputs Up To + 5 dB @ 0 dB Attenuation	DC – 2.0 GHz		>38		dBm
Return Loss*	Any Combination of Bits	DC - 4.0 GHz		11		dB
Attenuation Accuracy	All attenuation states	DC – 1.0 GHz	+/-(0.3 + 3% of programmed IL) dB		dB	
	All attenuation states	2.0 GHz	+/-(0.3 + 3% of programmed IL) dB		dB	
	All attenuation states	3.0 GHz	+/-(0.4 + 4% of programmed IL) d		dB	
	All attenuation states	4.0 GHz	+/-(0.	5 + 6% of program	med IL)	dB
Trise, Tfall*	10% To 90%	_		TBD		nS
Ton, Toff (Tpd)	50% Cntl To 90%/10%RF					nS
Transients	In-Band					mV

0.01uF Decoupling Capacitors Required On Power Supply Rails.

\*By design

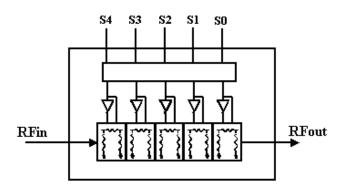
Web Site: www.mysoiservices.com
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#### **Functional Schematic**



## DC Electrical Specifications @ + 25°C

Parameter	Minimum	Typical	Maximum	Units
$V_{DD}$	3.3 1	5.0		V
V <sub>SS</sub>			-5.0	V
I <sub>DD</sub> Power Supply Current			2	mA
CMOS Logic level (0)	0		0.8	V
CMOS Logic level (1)	$V_{DD} - 0.8$		$V_{DD}$	V
Input Leakage Current			10	uA

Note 1, the performance curves are for Vdd = +5.0 +/-10%

## **Absolute Maximum Ratings<sup>2</sup>**

Parameter	Absolute Maximum	Units
Input Power	+ 35	dBm
V <sub>DD</sub>	+6.0	V
V <sub>SS</sub>	-5.5	V
ESD Voltage	400	V
Operating Temperature	-40 To +85	Degrees C
Storage Temperature	-65 To +125	Degrees C
(Digital Inputs	V <sub>DD</sub> +0.6 max to V <sub>SS</sub> -0.6 min	V

(Note 2) Operation of this Device beyond any of these parameters may cause permanent damage. **Latch-Up:** Unlike conventional CMOS digital attenuators, Honeywells' HRF-AT4520 is immune to latch-up.

**ESD Protection:** Although the HRF-AT4520 contains ESD protection circuitry on all digital inputs, conventional precautions should be taken to ensure that the Absolute Maximum Ratings are not exceeded.

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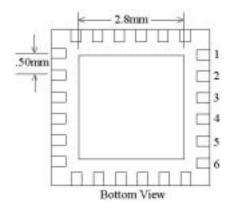
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### **Package Outline Drawing**



This package conforms to the LPCC<sup>IM</sup> 4 x 4 mm 24 lead body dimensions. See ASAT LPCC Marketing Outline Dwg. # DGMJ00004 Latest Rev. at <a href="http://www.asat.com">http://www.asat.com</a> for additional dimensional information.

### **Pin Configuration**

Pin	Function	Pin	Function	
1	VDD	13	GROUND	
2	GROUND	14	GROUND	
3	GROUND	15	RF OUTPUT	
4	RF INPUT	16	GROUND	
5	GROUND	17	VSS	
6	GROUND	18	DIGITAL GROUND	
7	GROUND	19	S0	
8	GROUND	20	S1	
9	GROUND	21	S2	
10	GROUND	22	S3	
11	GROUND	23	S4	
12	GROUND	24	OPEN	

#### **Truth Table**

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S4	S3	S2	S1	S0	Output
0	0	0	0	0	Reference Input
0	0	0	0	1	1 dB
0	0	0	1	0	2 dB
0	0	1	0	0	4 dB
0	1	0	0	0	8 dB
1	0	0	0	0	16 dB
1	1	1	1	1	31 dB

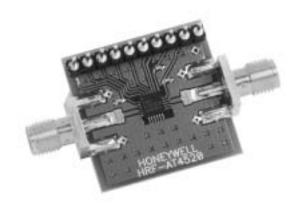
**Operation:** Data on parallel input "S" pins are independently buffered and presented to the RF attenuator circuits. "0" = CMOS Low, "1" = CMOS High.

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#### **Evaluation Circuit Board**



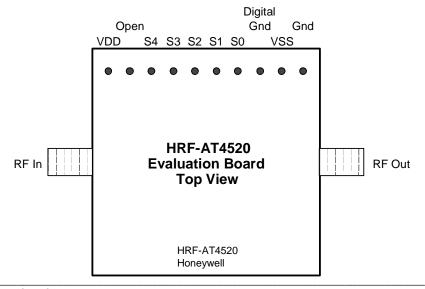
**HRF-AT4520 Evaluation Board** 

Honeywell's evaluation board provides an easy to use method of evaluating the RF performance of our attenuator. Simply connect power, DC and RF signals to be measuring switch performance in less than 10 minutes.

### **Evaluation Circuit Board Layout Design Details**

Item	Description
PCB	Impedance Matched Multi-Layer FR4
Attenuator	HRF-AT4520 Digital Attenuator
Chip Capacitor	Panasonic Model ECU-E1C103KBQ Capacitor, .01uf 0402 10% 16V
RF Connector	Johnson Connectors Model 142-0701-801 SMA RF Coaxial Connector
DC Pin	Mil-Max Model 800-10-064-10-001 Header Pins

#### **Evaluation Circuit Board Connections**



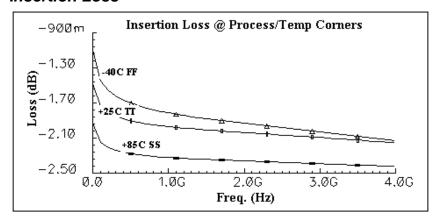
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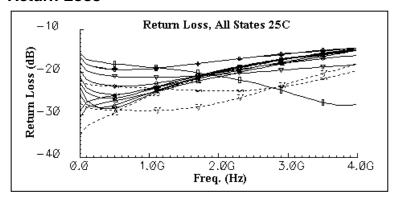
#### **Performance Curves**

#### **Insertion Loss**



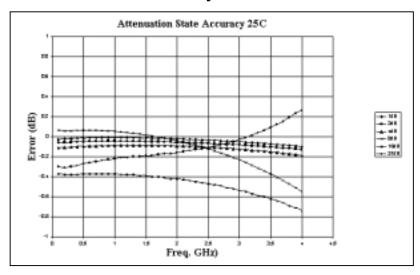
This Insertion Loss curve represents the Min/Max conditions for the "0" pass state versus all processing and temperature conditions. The Min case is at –40C with the "Fast" processing conditions. The Max case is at +85C with the "Slow" processing conditions. All other combinations fall within that band. The typical 25C case is labeled +25C TT.

#### Return Loss



This Return Loss set of curves represents the combination of all Return Loss cases for all attenuation settings. All cases are better than -14dB Return Loss at 4GHz.

#### Attenuation State Accuracy

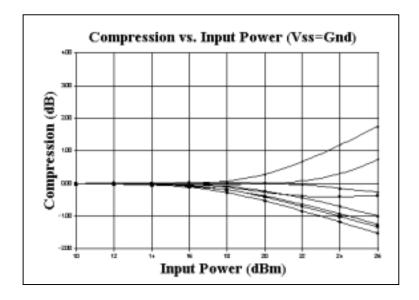


The Attenuation Accuracy curve with vertical axis of +/- 1dB shows all states better than +/- 0.5dB to 2GHz and better than +/- 0.8dB to 4GHz.

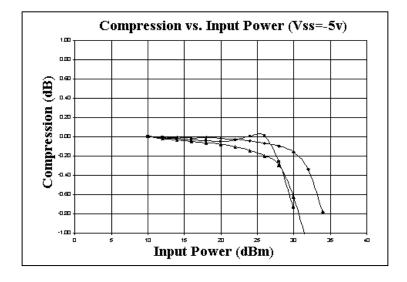
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#### Compression



The P1dB curve shows all states with a P1dB compression at approximately 23dB input power. The conditions for this curve are Vdd = +5.0v and Vss = 0v. For higher P1dB compression values, supply Vss with a negative voltage as shown in the next curve.



The P1dB curve shows all states with a P1dB compression at approximately 31dB input power. The conditions for this curve are Vdd = +5.0v and Vss = -5.0v.



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### **Ordering Information**

Ordering Number	Delivery Method	Units Per Shipment
HRF-AT4520-B	In Chip Tubes	Customer Specific, Usually Minimum
		Of 50 Per Chip Tube
HRF-AT4520-TR	On Tape And Reel <sup>3</sup>	Customer Specific
HRF-AT4520-E	On Individual Engineering Evaluation Board	One Board Per Box

(Note 3) Call Honeywell for details

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